



## Digital Transistors (Built-in Resistors)

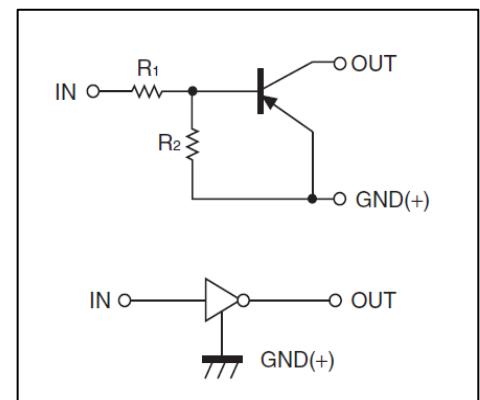
### DTA114EM/DTA114EE/DTA114EUA DTA114EKA /DTA114ECA/DTA114ESA

DIGITAL TRANSISTOR (PNP)

#### FEATURES

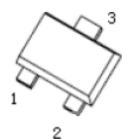
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

#### • Equivalent Circuit



#### PIN CONNECTIONS and MARKING

DTA114EM

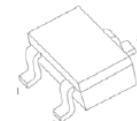


MARKING:14

SOT-723

1. IN
2. GND
3. OUT

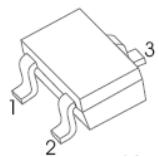
DTA114EE



SOT-523

1. IN
2. GND
3. OUT

DTA114EUA

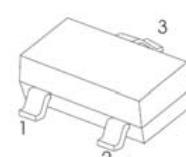


MARKING:14

SOT-323

1. IN
2. GND
3. OUT

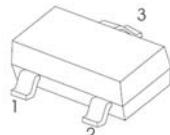
DTA114EKA



SOT-23-3L

1. IN
2. GND
3. OUT

DTA114ECA



MARKING:14

SOT-23

1. IN
2. GND
3. OUT

DTA114ESA



TO-92S

1. GND
2. OUT
3. IN

**MAXIMUM RATINGS(Ta=25°C unless otherwise noted)**

Symbol	Parameter	Limits(DTA114E□)						Unit
		M	E	UA	CA	KA	SA	
V <sub>cc</sub>	Supply Voltage	-50						V
V <sub>IN</sub>	Input Voltage	-40~+10						V
I <sub>O</sub>	Output Current	-50						mA
I <sub>CM</sub>	Peak Collector Current	-100						mA
P <sub>D</sub>	Power Dissipation	100	150	200	200	200	300	mW
T <sub>j</sub>	Junction Temperature	150						°C
T <sub>stg</sub>	Storage Temperature	-55~+150						°C

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Input voltage</b>	V <sub>I(off)</sub>	V <sub>CC</sub> =-5V,I <sub>O</sub> =-100μA	-0.5			V
	V <sub>I(on)</sub>	V <sub>O</sub> =-0.3V,I <sub>O</sub> =-10 mA			-3	V
<b>Output voltage</b>	V <sub>O(on)</sub>	I <sub>O</sub> /I <sub>I</sub> =-10mA/-0.5mA			-0.3	V
<b>Input current</b>	I <sub>I</sub>	V <sub>I</sub> =-5V			-0.88	mA
<b>Output current</b>	I <sub>O(off)</sub>	V <sub>CC</sub> =-50V,V <sub>I</sub> =0			-0.5	μA
<b>DC current gain</b>	G <sub>I</sub>	V <sub>O</sub> =-5V,I <sub>O</sub> =-5mA	30			
<b>Input resistance</b>	R <sub>1</sub>		7	10	13	kΩ
<b>Resistance ratio</b>	R <sub>2/R<sub>1</sub></sub>		0.8	1	1.2	
<b>Transition frequency</b>	f <sub>T</sub>	V <sub>O</sub> =-10V,I <sub>O</sub> =-5mA,f=100MHz		250		MHz

# Typical Characteristics

DTA114EXX

